

SuperMOS –FDFN3*3-8L 30V BV_{DSS}, 15mΩ R_{DS(on)}, N-channel MOSFET

1. Description

The ESN4842 is N-Channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent R_{DS(ON)} with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product ESN4842 is Pb-free.

2. Features

- 30V, R_{DS(ON)}=15mΩ(TYP.) @V_{GS}=10V
R_{DS(ON)}=24mΩ(TYP.) @V_{GS}=4.5V
 - Use trench MOSFET technology
 - High density cell design for low R_{DS(on)}
- Material: Halogen free
 - Reliable and rugged
 - Avalanche Rated
 - Low leakage current

3. Applications

- PWM applications
 - Load switch
 - Power management in portable/desktop PCs
 - DC/DC conversion
- 100% UIS TESTED

4. Ordering Information

Part Number	Package	Marking	Material	Packing	Quantity per reel	Flammability Rating	Reel Size
ESN4842	FDFN3*3-8L	ESN4842/lot	Halogen free	Tape & Reel	5,000 PCS	UL 94V-0	13 inches

Table-1 Ordering information

5. Pin Configuration and Functions

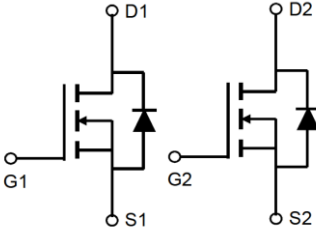
Pin	Function	Outline	Circuit Diagram
1	Source1		
2	Gate1		
7/8	Drain1		
3	Source2		
4	Gate2		
5/6	Drain2		

Table-2 Pin configuration

6. Specification

Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		BV_{DSS}	30	V
Gate-Source Voltage		V_{GS}	± 20	V
Continuous Drain Current	$T_C=25^{\circ}\text{C}$	I_D	30	A
	$T_C=75^{\circ}\text{C}$		23	
Maximum Power Dissipation	$T_C=25^{\circ}\text{C}$	P_D	30	W
	$T_C=75^{\circ}\text{C}$		18	
Pulsed Drain Current ^a		I_{DM}	120	A
Avalanche Current, Single Pulsed ^b		I_{AS}	11	A
Avalanche Energy, Single Pulsed ^b		E_{AS}	18	mJ
Operating Junction Temperature		T_J	150	°C
Lead Temperature		T_L	260	°C
Storage Temperature Range		T_{stg}	-55 to 150	°C

Thermal resistance ratings

Single Operation			
Parameter	Symbol	Typical	Unit
Junction-to-Case Thermal Resistance ^a	$R_{\theta JC}$	4.2	°C/W

Note:

a: Surface mounted on FR4 Board using 1 square inch pad size, 1oz copper

b: $T_J=25^{\circ}\text{C}$, $V_{DD}=30\text{V}$, $V_G=10\text{V}$, $L=0.3\text{mH}$, $R_g=25\Omega$

Electrical Characteristics

At TA = 25°C unless otherwise specified

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	30			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V			1.0	uA
Gate-to-source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{GS} =V _{DS} , I _D =250uA	1.0	1.5	2.2	V
Drain-to-source On-resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A		15	22	mΩ
		V _{GS} =4.5V, I _D =15A		24	36	
Forward Trans conductance	g _{FS}	V _{DS} =5.0V, I _D =20A			100	S
CHARGES, CAPACITANCES AND GATE RESISTANCE						
Input Capacitance	C _{ISS}	V _{GS} =0V, f=1MHz, V _{DS} =15V		373	448	pF
Output Capacitance	C _{OSS}			67		
Reverse Transfer Capacitance	C _{RSS}			41		
Total Gate Charge	Q _{G(TOT)}	V _{GS} =10V, V _{DS} =15V, I _D =20A		7.2	11	nC
Gate-to-Source Charge	Q _{GS}			14.9		
Gate-to-Drain Charge	Q _{GD}			2.9		
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	t _{d(ON)}	V _{GS} =10V, V _{DS} =15V, R _L =1.95Ω, R _{GEN} =3Ω		4.5		ns
Rise Time	t _r			2.7		
Turn-Off Delay Time	t _{d(OFF)}			14.9		
Fall Time	t _f			2.9		
BODY DIODE CHARACTERISTICS						
Forward Voltage	V _{SD}	V _{GS} =0V, I _S =1.0A	0.45		1.5	V

7. Typical Characteristic

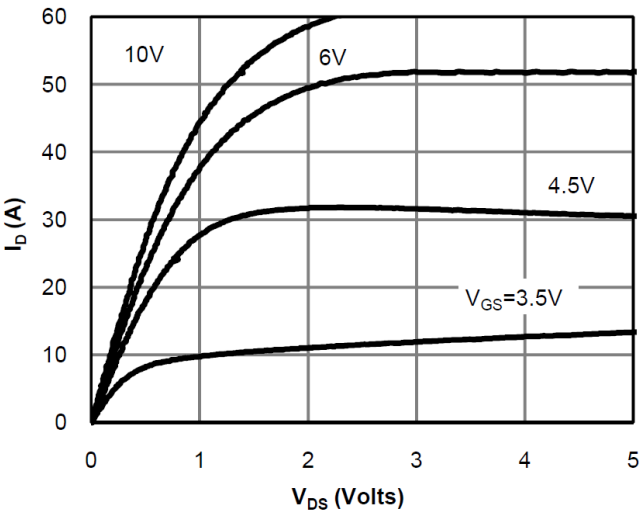


Fig 1: On-Region Characteristics

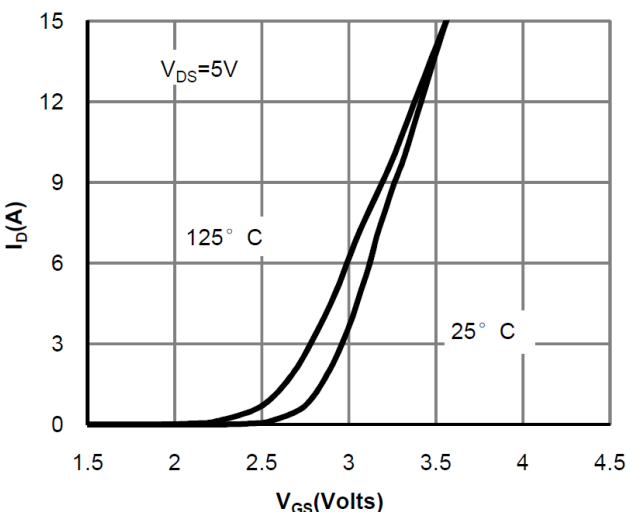


Figure 2: Transfer Characteristics

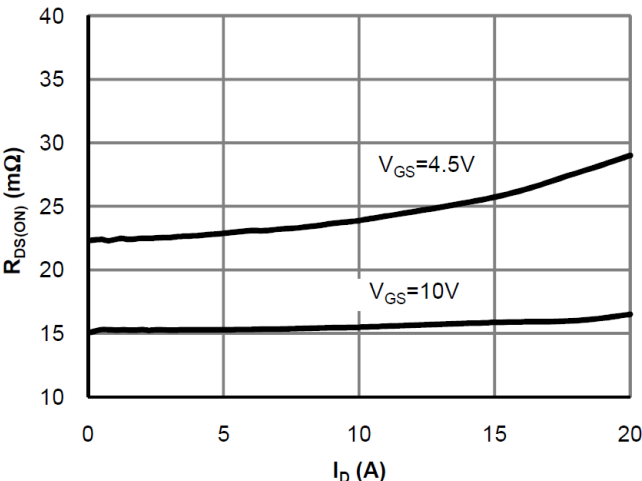


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

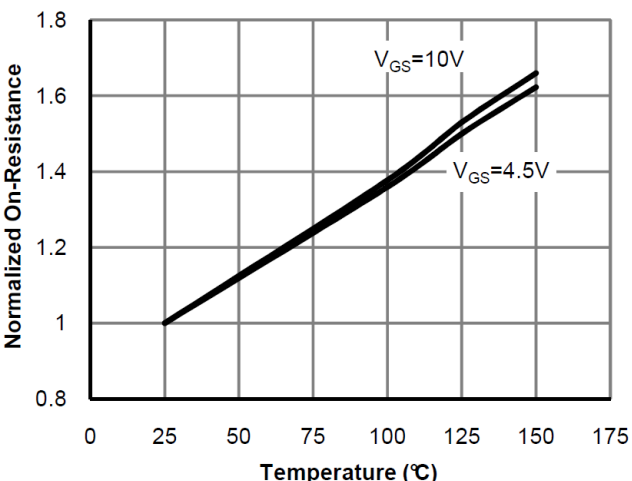


Figure 4: On-Resistance vs. Junction Temperature

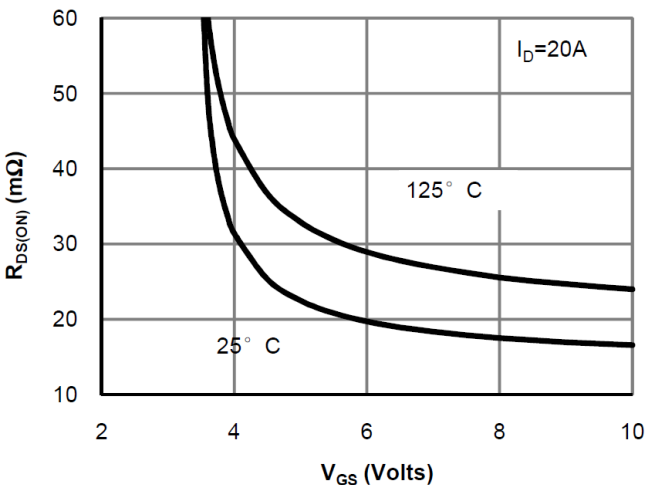


Figure 5: On-Resistance vs. Gate-Source Voltage

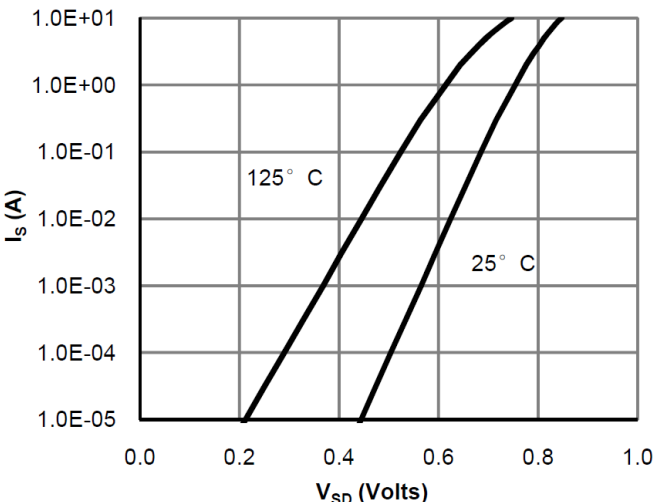
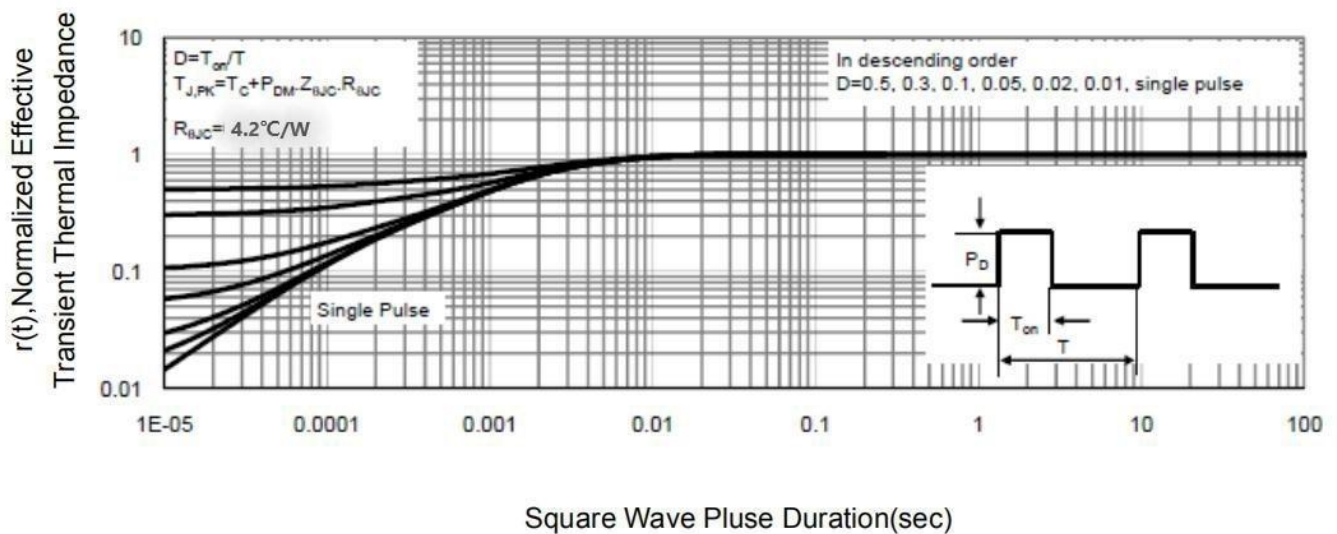
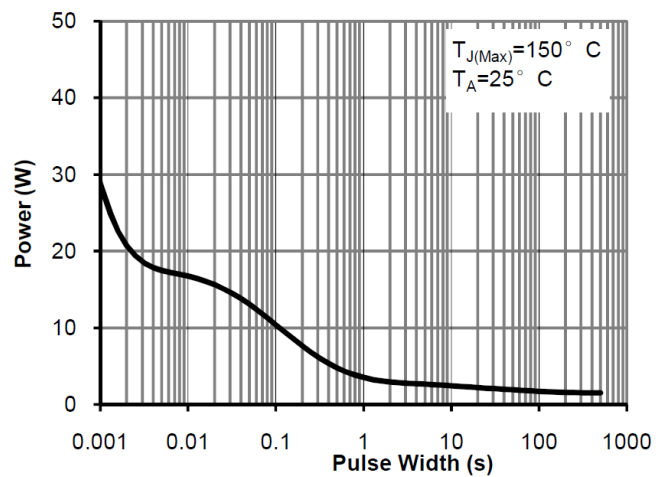
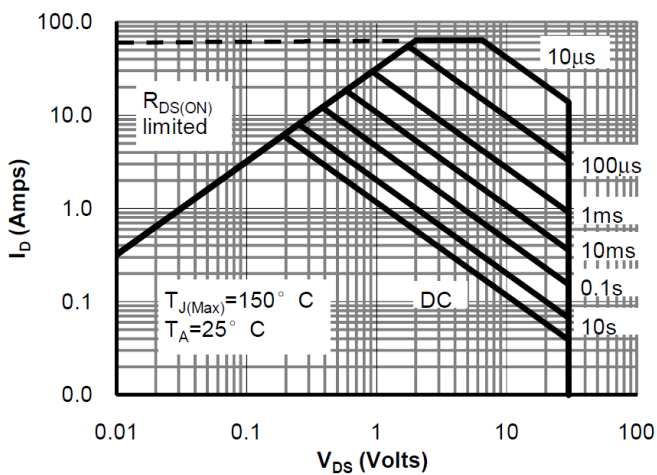
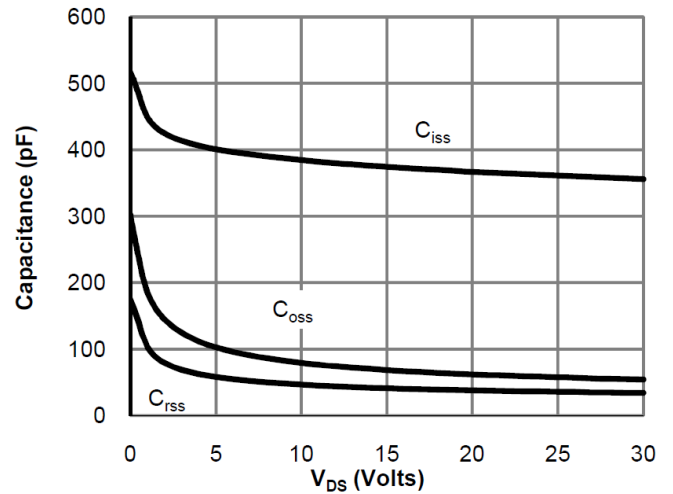
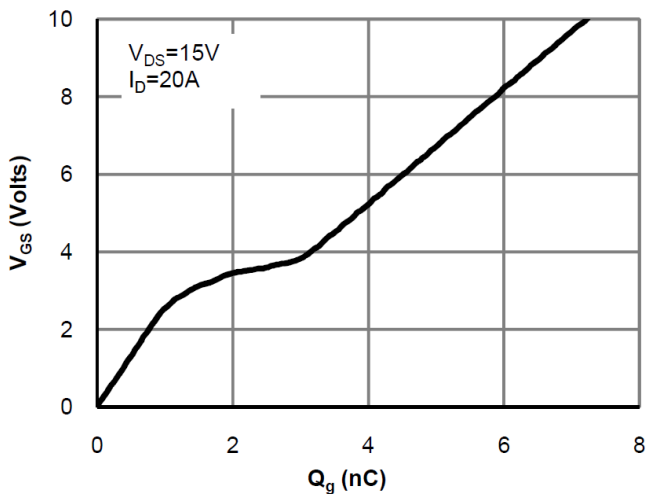
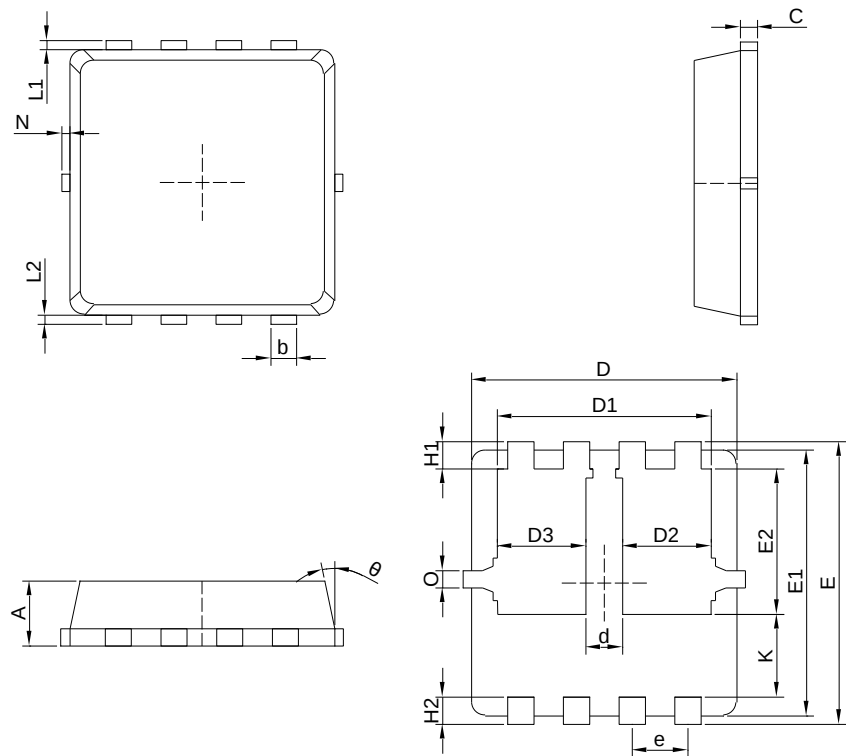


Figure 6: Body-Diode Characteristics



8. Dimension (FDFN3*3-8L)



Symbol	Dimensions in Millimeters			Symbol	Dimensions in Millimeters		
	MIN	NOM	MAX		MIN	NOM	MAX
A	0.65	0.75	0.85	E2	1.72	1.82	1.92
b	0.25	0.30	0.35	e	0.65 BSC.		
C	0.15	0.20	0.25	H1	0.21	0.31	0.41
D	3.00	3.10	3.20	H2	0.30	0.40	0.50
D1	2.40	2.50	2.60	K	0.67	0.77	0.87
D2/D3	1.00	1.05	1.10	L1/L2	0.10 REF.		
d	0.30	0.40	0.50	theta	11°	12°	13°
E	3.20	3.30	3.40	N	0	-	0.15
E1	3.00	3.10	3.20	O	0.2 REF.		

DISCLAIMER

ELECSUPER PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with ElecSuper products. You are solely responsible for

- (1) selecting the appropriate ElecSuper products for your application;
- (2) designing, validating and testing your application;
- (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements.

These resources are subject to change without notice. ElecSuper grants you permission to use these resources only for development of an application that uses the ElecSuper products described in the resource. Other reproduction and display of these resources are prohibited. No license is granted to any other ElecSuper intellectual property right or to any third party intellectual property right. ElecSuper disclaims responsibility for, and you will fully indemnify ElecSuper and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources. ElecSuper's products are provided subject to ElecSuper's Terms of Sale or other applicable terms available either on www.elecsuper.com or provided in conjunction with such ElecSuper products. ElecSuper's provision of these resources does not expand or otherwise alter ElecSuper's applicable warranties or warranty disclaimers for ElecSuper products.